

# PBSS4041SN

# 60 V, 6.7 A NPN/NPN low V<sub>CEsat</sub> (BISS) transistor Rev. 2 — 18 October 2010 Pro

Product data sheet

#### 1. **Product profile**

#### 1.1 General description

NPN/NPN low V<sub>CEsat</sub> Breakthrough In Small Signal (BISS) transistor in a SOT96-1 (SO8) medium power Surface-Mounted Device (SMD) plastic package.

Table 1. **Product overview** 

| Type number | Package F |      | PNP/PNP    | NPN/PNP     |
|-------------|-----------|------|------------|-------------|
|             | Nexperia  | Name | complement | complement  |
| PBSS4041SN  | SOT96-1   | SO8  | PBSS4041SP | PBSS4041SPN |

#### 1.2 Features and benefits

- Very low collector-emitter saturation voltage V<sub>CEsat</sub>
- High collector current capability I<sub>C</sub> and I<sub>CM</sub>
- High collector current gain (h<sub>FF</sub>) at high I<sub>C</sub>
- High efficiency due to less heat generation
- Smaller required Printed-Circuit Board (PCB) area than for conventional transistors

#### 1.3 Applications

- Loadswitch
- Battery-driven devices
- Power management
- Charging circuits
- Power switches (e.g. motors, fans)

#### 1.4 Quick reference data

Table 2. Quick reference data

| Symbol             | Parameter                               | Conditions                           | Min   | Тур | Max | Unit |
|--------------------|---|--------------------------------------|-------|-----|-----|------|
| $V_{\text{CEO}}$   | collector-emitter voltage               | open base                            | -     | -   | 60  | V    |
| I <sub>C</sub>     | collector current                       |                                      | -     | -   | 6.7 | Α    |
| I <sub>CM</sub>    | peak collector current                  | single pulse; $t_p \le 1 \text{ ms}$ | -     | -   | 15  | Α    |
| R <sub>CEsat</sub> | collector-emitter saturation resistance | $I_C = 4 A; I_B = 0.2 A$             | [1] _ | 32  | 48  | mΩ   |

<sup>[1]</sup> Pulse test:  $t_p \le 300 \ \mu s; \ \delta \le 0.02.$ 



### 2. Pinning information

Table 3. Pinning

|     | 3             |                    |                |
|-----|---------------|--------------------|----------------|
| Pin | Description   | Simplified outline | Graphic symbol |
| 1   | emitter TR1   |                    |                |
| 2   | base TR1      | 8月月月5              | 8 7 6 5        |
| 3   | emitter TR2   |                    | TR1 L TR2 L    |
| 4   | base TR2      |                    |                |
| 5   | collector TR2 | 1 H H H 4          | 1 2 3 4        |
| 6   | collector TR2 |                    | 006aaa966      |
| 7   | collector TR1 |                    |                |
| 8   | collector TR1 |                    |                |
|     |               |                    |                |

### 3. Ordering information

Table 4. Ordering information

| Type number | Package | Package Package   |         |  |
|-------------|---------|---|---------|--|
|             | Name    | Description   | Version |  |
| PBSS4041SN  | SO8     | plastic small outline package; 8 leads; body width 3.9 mm | SOT96-1 |  |

### 4. Marking

Table 5. Marking codes

| Type number | Marking code |
|-------------|--------------|
| PBSS4041SN  | 4041SN       |

### 5. Limiting values

Table 6. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

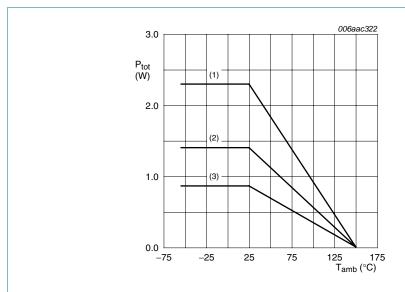
| Symbol           | Parameter                 | Conditions                           | Min          | Max  | Unit |
|------------------|---------------------------|--------------------------------------|--------------|------|------|
| Per transis      | stor                      |                                      |              |      |      |
| $V_{CBO}$        | collector-base voltage    | open emitter                         | -            | 60   | V    |
| $V_{CEO}$        | collector-emitter voltage | open base                            | -            | 60   | V    |
| $V_{EBO}$        | emitter-base voltage      | open collector                       | -            | 5    | V    |
| I <sub>C</sub>   | collector current         |                                      | -            | 6.7  | Α    |
| I <sub>CM</sub>  | peak collector current    | single pulse; $t_p \le 1 \text{ ms}$ | -            | 15   | Α    |
| $I_B$            | base current              |                                      | -            | 1    | Α    |
| P <sub>tot</sub> | total power dissipation   | $T_{amb} \le 25  ^{\circ}C$          | <u>[1]</u> _ | 0.73 | W    |
|                  |                           |                                      | [2] _        | 1    | W    |
|                  |                           |                                      | [3]          | 1.7  | W    |

 Table 6.
 Limiting values ...continued

In accordance with the Absolute Maximum Rating System (IEC 60134).

| Symbol           | Parameter               | Conditions                  | Min          | Max  | Unit |
|------------------|-------------------------|-----------------------------|--------------|------|------|
| Per device       | )                       |                             |              |      |      |
| P <sub>tot</sub> | total power dissipation | $T_{amb} \le 25  ^{\circ}C$ | <u>[1]</u> - | 0.86 | W    |
|                  |                         |                             | [2] _        | 1.4  | W    |
|                  |                         |                             | [3] _        | 2.3  | W    |
| Tj               | junction temperature    |                             | -            | 150  | °C   |
| T <sub>amb</sub> | ambient temperature     |                             | <b>–55</b>   | +150 | °C   |
| $T_{stg}$        | storage temperature     |                             | -65          | +150 | °C   |

- [1] Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.
- [2] Device mounted on an FR4 PCB, single-sided copper, tin-plated, mounting pad for collector 1 cm<sup>2</sup>.
- [3] Device mounted on a ceramic PCB, Al<sub>2</sub>O<sub>3</sub>, standard footprint.



- (1) Ceramic PCB,  $Al_2O_3$ , standard footprint
- (2) FR4 PCB, mounting pad for collector 1 cm<sup>2</sup>
- (3) FR4 PCB, standard footprint

Fig 1. Per device: Power derating curves

### 6. Thermal characteristics

Table 7. Thermal characteristics

| Symbol   | Parameter  | Conditions  | Min          | Тур | Max | Unit |
|--|--|-------------|--------------|-----|-----|------|
| Per trans  | sistor   |             |              |     |     |      |
| $R_{\text{th(j-a)}}$ thermal resistance from junction to ambient | thermal resistance from                          | in free air | <u>[1]</u> - | -   | 170 | K/W  |
|  |  | [2] _       | -            | 125 | K/W |      |
|  |  |             | [3]          | -   | 75  | K/W  |
| $R_{th(j-sp)}$   | thermal resistance from junction to solder point |             | -            | -   | 40  | K/W  |
| Per devid  | e  |             |              |     |     |      |
| R <sub>th(j-a)</sub>   | thermal resistance from                          | in free air | [1] -        | -   | 145 | K/W  |
|  | junction to ambient                              |             | [2] _        | -   | 90  | K/W  |
| _  |  |             | [3] _        | -   | 55  | K/W  |
|  |  |             |              |     |     |      |

- [1] Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.
- [2] Device mounted on an FR4 PCB, single-sided copper, tin-plated, mounting pad for collector 1 cm<sup>2</sup>.
- [3] Device mounted on a ceramic PCB, Al<sub>2</sub>O<sub>3</sub>, standard footprint.

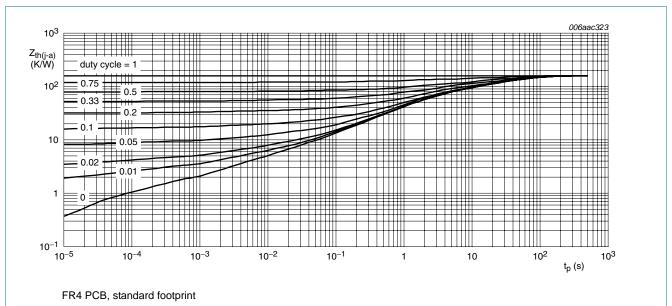
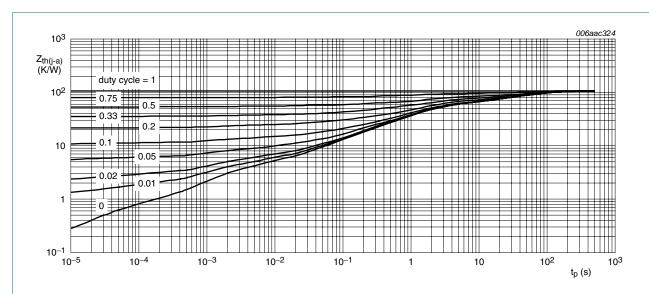
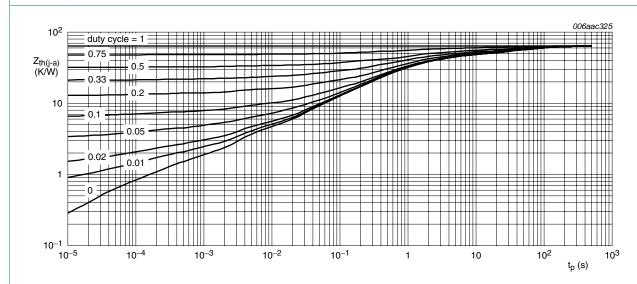


Fig 2. Per transistor: Transient thermal impedance from junction to ambient as a function of pulse duration; typical values



FR4 PCB, mounting pad for collector 1 cm<sup>2</sup>

Fig 3. Per transistor: Transient thermal impedance from junction to ambient as a function of pulse duration; typical values



Ceramic PCB, Al<sub>2</sub>O<sub>3</sub>, standard footprint

Fig 4. Per transistor: Transient thermal impedance from junction to ambient as a function of pulse duration; typical values

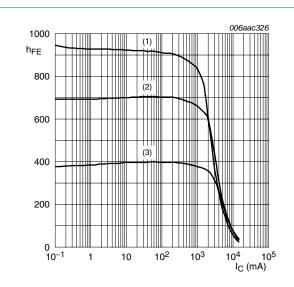
### 7. Characteristics

Table 8. Characteristics

 $T_{amb} = 25$  °C unless otherwise specified.

| Symbol             | Parameter                                     | Conditions  |     | Min | Тур  | Max  | Unit |
|--------------------|---|---|-----|-----|------|------|------|
| Per tran           | sistor  |   |     |     |      |      |      |
| I <sub>CBO</sub>   | collector-base                                | $V_{CB} = 60 \text{ V}; I_E = 0 \text{ A}$                            |     | -   | -    | 100  | nΑ   |
|                    | cut-off current                               | $V_{CB} = 60 \text{ V}; I_E = 0 \text{ A};$<br>$T_j = 150 \text{ °C}$ |     | -   | -    | 50   | μΑ   |
| I <sub>CES</sub>   | collector-emitter cut-off current             | $V_{CE} = 48 \text{ V}; V_{BE} = 0 \text{ V}$                         |     | -   | -    | 100  | nA   |
| I <sub>EBO</sub>   | emitter-base<br>cut-off current               | $V_{EB} = 5 \text{ V}; I_{C} = 0 \text{ A}$                           |     | -   | -    | 100  | nA   |
| h <sub>FE</sub>    | DC current gain                               | V <sub>CE</sub> = 2 V   | [1] |     |      |      |      |
|                    |   | $I_C = 500 \text{ mA}$  |     | 300 | 500  | -    |      |
|                    |   | I <sub>C</sub> = 1 A  |     | 300 | 500  | -    |      |
|                    |   | I <sub>C</sub> = 2 A  |     | 250 | 450  | -    |      |
|                    |   | I <sub>C</sub> = 4 A  |     | 150 | 250  | -    |      |
|                    |   | I <sub>C</sub> = 6 A  |     | 75  | 150  | -    |      |
| $V_{CEsat}$        | collector-emitter                             |   | [1] |     |      |      |      |
|                    | saturation voltage                            | I <sub>C</sub> = 1 A; I <sub>B</sub> = 50 mA                          |     | -   | 40   | 60   | mV   |
|                    | I <sub>C</sub> = 1 A; I <sub>B</sub> = 10 mA  |   | -   | 65  | 100  | mV   |      |
|                    | I <sub>C</sub> = 2 A; I <sub>B</sub> = 40 mA  |   | -   | 85  | 145  | mV   |      |
|                    | I <sub>C</sub> = 4 A; I <sub>B</sub> = 200 mA |   | -   | 125 | 190  | mV   |      |
|                    |   | I <sub>C</sub> = 4 A; I <sub>B</sub> = 40 mA                          |     | -   | 220  | 320  | mV   |
|                    |   | I <sub>C</sub> = 7 A; I <sub>B</sub> = 350 mA                         |     | -   | 230  | 350  | mV   |
| R <sub>CEsat</sub> | collector-emitter saturation resistance       | $I_C = 4 \text{ A}; I_B = 200 \text{ mA}$                             | [1] | -   | 32   | 48   | mΩ   |
| $V_{BEsat}$        | base-emitter                                  |   | [1] |     |      |      |      |
|                    | saturation voltage                            | I <sub>C</sub> = 1 A; I <sub>B</sub> = 100 mA                         |     | -   | 0.86 | 1    | V    |
|                    |   | I <sub>C</sub> = 4 A; I <sub>B</sub> = 400 mA                         |     | -   | 1.05 | 1.2  | V    |
| $V_{BEon}$         | base-emitter<br>turn-on voltage               | $V_{CE} = 2 \text{ V}; I_{C} = 2 \text{ A}$                           | [1] | -   | 0.75 | 0.85 | V    |
| t <sub>d</sub>     | delay time                                    | $V_{CC} = 12.5 \text{ V}; I_C = 1 \text{ A};$                         |     | -   | 35   | -    | ns   |
| t <sub>r</sub>     | rise time                                     | $I_{Bon} = 0.05 \text{ A}; I_{Boff} = -0.05 \text{ A}$                |     | -   | 65   | -    | ns   |
| t <sub>on</sub>    | turn-on time                                  |   |     | -   | 100  | -    | ns   |
| ts                 | storage time                                  |   |     | -   | 1050 | -    | ns   |
| t <sub>f</sub>     | fall time                                     |   |     | -   | 220  | -    | ns   |
| t <sub>off</sub>   | turn-off time                                 |   |     | -   | 1270 | -    | ns   |
| f <sub>T</sub>     | transition frequency                          | $V_{CE} = 10 \text{ V}; I_{C} = 100 \text{ mA};$ f = 100 MHz          |     | -   | 130  | -    | MHz  |
| C <sub>c</sub>     | collector capacitance                         | $V_{CB} = 10 \text{ V}; I_E = i_e = 0 \text{ A};$<br>f = 1 MHz        |     | -   | 35   | -    | pF   |

<sup>[1]</sup> Pulse test:  $t_p \le 300 \ \mu s; \ \delta \le 0.02.$ 



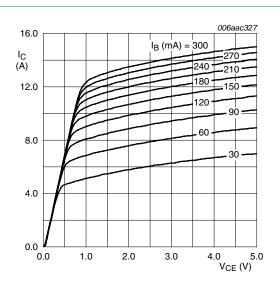
$$V_{CE} = 2 V$$

(1) 
$$T_{amb} = 100 \, ^{\circ}C$$

(2) 
$$T_{amb} = 25 \, ^{\circ}C$$

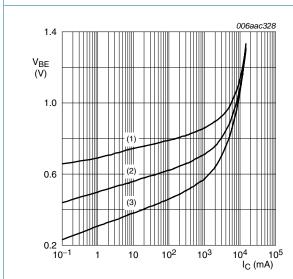
(3)  $T_{amb} = -55 \, ^{\circ}C$ 

Fig 5. DC current gain as a function of collector current; typical values



T<sub>amb</sub> = 25 °C

Fig 6. Collector current as a function of collector-emitter voltage; typical values



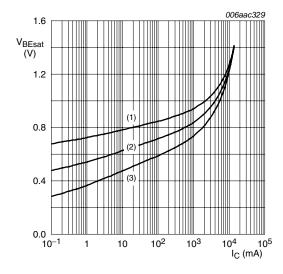


(1) 
$$T_{amb} = -55 \, ^{\circ}C$$

(2) 
$$T_{amb} = 25 \, ^{\circ}C$$

(3)  $T_{amb} = 100 \, ^{\circ}C$ 

Fig 7. Base-emitter voltage as a function of collector current; typical values



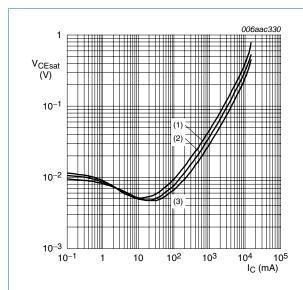
$$I_{\rm C}/I_{\rm B} = 20$$

(1) 
$$T_{amb} = -55 \,^{\circ}C$$

(2)  $T_{amb} = 25 \, ^{\circ}C$ 

(3)  $T_{amb} = 100 \, ^{\circ}C$ 

Fig 8. Base-emitter saturation voltage as a function of collector current; typical values



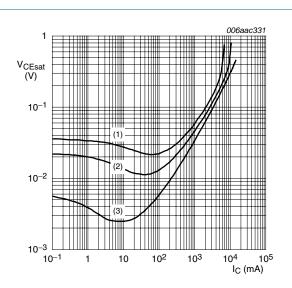
$$I_{\rm C}/I_{\rm B} = 20$$

(1) 
$$T_{amb} = 100 \, ^{\circ}C$$

(2) 
$$T_{amb} = 25 \, ^{\circ}C$$

(3)  $T_{amb} = -55 \, ^{\circ}C$ 

Fig 9. Collector-emitter saturation voltage as a function of collector current; typical values



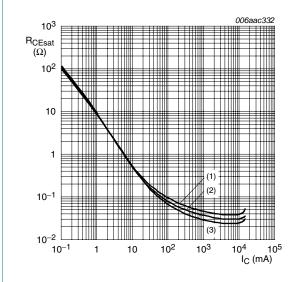
$$T_{amb} = 25 \, ^{\circ}C$$

(1) 
$$I_C/I_B = 100$$

(2) 
$$I_C/I_B = 50$$

(3) 
$$I_C/I_B = 10$$

Fig 10. Collector-emitter saturation voltage as a function of collector current; typical values



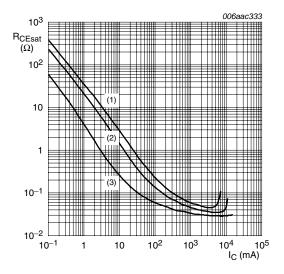
 $I_{\rm C}/I_{\rm B} = 20$ 

(1) 
$$T_{amb} = 100 \, ^{\circ}C$$

(2) 
$$T_{amb} = 25 \, ^{\circ}C$$

(3)  $T_{amb} = -55 \, ^{\circ}C$ 

Fig 11. Collector-emitter saturation resistance as a function of collector current; typical values



T<sub>amb</sub> = 25 °C

(1) 
$$I_C/I_B = 100$$

(2)  $I_C/I_B = 50$ 

(3)  $I_C/I_B = 10$ 

Fig 12. Collector-emitter saturation resistance as a function of collector current; typical values

### 8. Test information

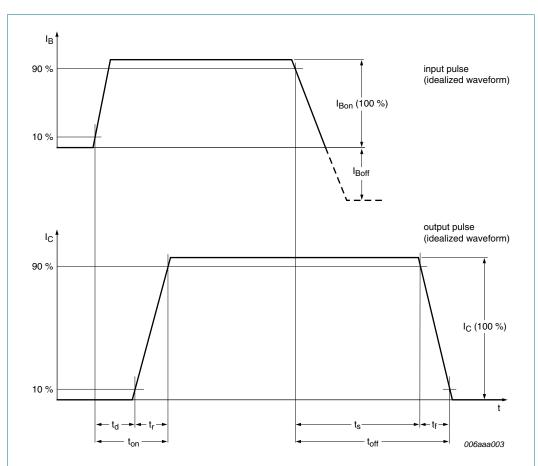
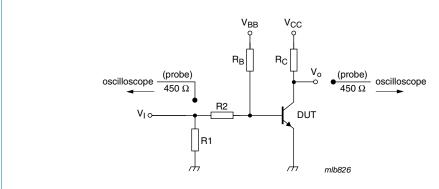


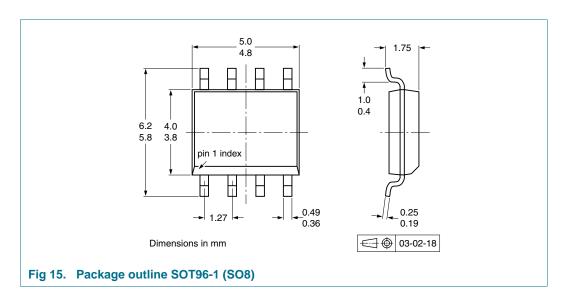
Fig 13. BISS transistor switching time definition



 $V_{CC}$  = 12.5 V;  $I_{C}$  = 1 A;  $I_{Bon}$  = 0.05 A;  $I_{Boff}$  = -0.05 A

Fig 14. Test circuit for switching times

### 9. Package outline



### 10. Packing information

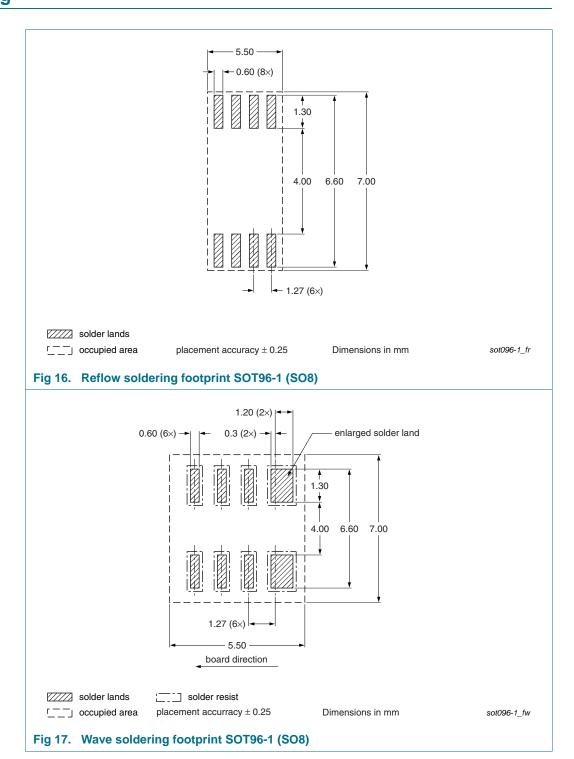
Table 9. Packing methods

The indicated -xxx are the last three digits of the 12NC ordering code.[1]

| Type number | Package | Description                     | Packing | quantity |
|-------------|---------|---------------------------------|---------|----------|
|             |         |                                 | 1000    | 2500     |
| PBSS4041SN  | SOT96-1 | 8 mm pitch, 12 mm tape and reel | -115    | -118     |

<sup>[1]</sup> For further information and the availability of packing methods, see Section 14.

### 11. Soldering



### 12. Revision history

#### Table 10. Revision history

| Document ID    | Release date   | Data sheet status              | Change notice | Supersedes     |
|----------------|----------------|--------------------------------|---------------|----------------|
| PBSS4041SN v.2 | 20101018       | Product data sheet             | -             | PBSS4041SN v.1 |
| Modifications: | • Figure 1 "Pe | r device: Power derating curve | s": updated.  |                |
| PBSS4041SN v.1 | 20100714       | Product data sheet             | -             | -              |

### 13. Legal information

#### 13.1 Data sheet status

| Document status[1][2]          | Product status[3] | Definition  |
|--------------------------------|-------------------|---|
| Objective [short] data sheet   | Development       | This document contains data from the objective specification for product development. |
| Preliminary [short] data sheet | Qualification     | This document contains data from the preliminary specification.                       |
| Product [short] data sheet     | Production        | This document contains the product specification.                                     |

- [1] Please consult the most recently issued document before initiating or completing a design.
- [2] The term 'short data sheet' is explained in section "Definitions"
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Nexperia PBSS4041SN

60 V, 6.7 A NPN/NPN low V<sub>CEsat</sub> (BISS) transistor

**Quick reference data** — The Quick reference data is an extract of the product data given in the Limiting values and Characteristics sections of this document, and as such is not complete, exhaustive or legally binding.

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**PBSS4041SN** 

60 V, 6.7 A NPN/NPN low V<sub>CEsat</sub> (BISS) transistor

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